Hologram Lasers GH5R495A3C

# **GH5R495A3C**

#### ■ Features

- (1) High power output (pulse MAX. 121mW)
- (2) For ×16 speed CD-R, ×40 speed CD-ROM (With built-in MIN. 45MHz OPIC\*)
- (3) High coupling efficiency The ellipticity  $(\theta \perp / \theta / \ell)$  is close to 1.
- (4) \$\phi 4.8mm\$ thickness
- (5) With built-in beam splitter and diffraction grating

\*OPIC: (Optical IC) is a trademark of SHARP Corporation.

An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

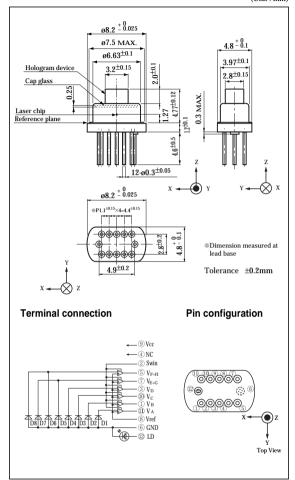
# Applications

- (1) CD-R drives
- (2) CD-RW drives

# High Power Output Hologram Laser for ×16 Speed CD-R Drive

#### Outline Dimensions

(Unit: mm)



### ■ Absolute Maximum Ratings

\*1

Parame	Symbol	Rating	Unit	
Optical power outpo	Рнс	85	mW	
Optical power outpo	ıt (pulse)	Рнр	121	mW
Daviana valtada	Lagan	V-	9	3.7

*2 Optical power output	ıt (pulse)	P <sub>HP</sub>	121	mW
Reverse voltage	Reverse voltage Laser			V
OPIC supply voltag	e	Vcc	6	V
*3 Operating temperat	ure	Topr	0 to +60	°C
*3 Storage temperatur	Tstg	-40 to +85	°C	
*4 Soldering temperat	ure	Tsold	260	°C

<sup>&</sup>lt;sup>®1</sup> Output power from hologram laser Equivalent to 95mW (CW) from cap glass

#### SHARP

(Tc=25°C)

Output power from hologram laser Equivalent to 135mW (pulse) from cap glass (pulse width: 0.5μs, Duty: 50%)

<sup>\*3</sup> Case temperature \*4 At the position of 1.6mm from the lead base (Within 5s)

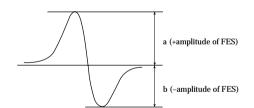
# **■** Electro-optical Characteristics

 $(Tc=25^{\circ}C)$ 

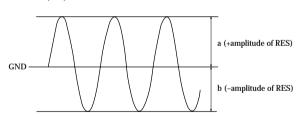
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Focal offset	DEF	Collimated lens output power 1.5mW, High gain	-0.7	-	+0.7	μm
*2 Focal error symmetry	Bres	Collimated lens output power 1.5mW, High gain	-25	-	+25	%
*3 Radial error balance	Bres	Collimated lens output power 1.5mW, High gain	-25	-	+25	%
*4 RF output amplitude	Vrf	Collimated lens output power 1.5mW, High gain	0.65	0.94	1.23	V
*5 FES output amplitude	VFES	Collimated lens output power 1.5mW, High gain	0.35	0.59	0.94	V
*6 RES output amplitude	Vres	Collimated lens output power 1.5mW, High gain	0.09	0.19	0.30	V
*7 Main spot balance	MSB	Collimated lens output power 1.5mW, High gain	80	100	120	%
*8 Sub spot balance	SSB	Collimated lens output power 1.5mW, High gain	80	100	120	%
Jitter	JIT	Collimated lens output power 1.5mW, High gain	-	-	23	ns
Threshold current	Ith	-	-	30	40	mA
Operating current	Iop	Po=80mW	-	120	145	mA
Operating voltage	Vop	Po=80mW	-	2.2	2.5	V
Wavelength	$\lambda_p$	Po=80mW	773	784	797	nm
Differential efficiency	ηα	70mW I(80mW)-I(10mW)	0.7	0.85	1.2	mW/mA

<sup>\*1</sup> Distance between FES=0 and jitter minimum point

\*2 (a-b) / (a+b)



$$\frac{a-b}{2\times(a+b)}$$



- \*\*4 Amplitude of Va+Vb+Vc+VD (focal servo ON, radial servo ON)
- \*5 VB-VA (Focal vibration)
- Maplitude of (Vc-VD)-k1(VE+G-VF+H). k1=(Vc+VD)/(VE+G+VF+H)=1 When tracking servo is ON, (Vc-VD)-k1(VE+G-VF+H)+α should be 0.
- \*7 (VA+VB) / (VC+VD)
- \*\*8 Vc/VD

# ■ Electro-optical Characteristics of Laser Diode (Design Standard\*)

 $(Tc=25^{\circ}C)$ 

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Stability of differe	Stability of differential efficiency		$\Delta\eta_d$	Po=10 to 135mW	-	-	40	%
Half intensity one	Half intensity angle Parall Perpendic		θ//		8	9	10	۰
rian intensity ang			$\theta \perp$	D 05 W	15	17	19	۰
Emission	Deviation	Parallel	ø//	Po=95mW	-2	-	+2	۰
characteristics	angle	Perpendicular	ø⊥		-3	-	+3	۰
Beam shift		$\Delta \emptyset //$	ø//(95mW)-ø//(3mW)	-1	-	+1	۰	
Kink		K-LI	P1=27mW, P2=81mW, P3=135mW	-	-	15	%	

# ■ Electro-optical Characteristics of OPIC for Signal Detection\*9

(Tc= $25^{\circ}$ C, Vcc=5V, Vref=2.1V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*10 Segment
Supply current	Icc1	High gain, Gain switching SW=H	-	20	25	mA	
	Icc2	Low gain, Gain switching SW=L	-	30	35	mA	
*11 Output offset voltage	Vod	Common to high/low gain, No light	-25	2	+25	mV	A, B
Offset voltage difference, Gain switching	$\Delta V_{od}$	Common to high/low gain	-30	-	+30	mV	A, B

 $<sup>^{99}</sup>$  0.1 $\mu$ F or more capacitor should be added between OPIC power supply terminal and GND, Vref terminal and GND. (at the position of 10mm or less from the lead base)

A: VA, VB, VC, VD

B: VE+G, VF+H

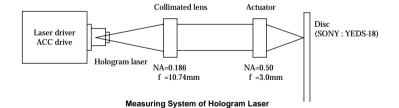
\*11 Difference from Vref

## ■ Electro-optical Characteristics of Hologram Laser (Design Standard\*)\*1

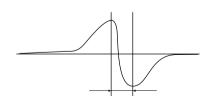
(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*2 Focal error signal capture range	-	_	-	14	-	μm
Focal error signal sensitivity	-	_	-	13	-	%/µm

**#1** 



\*2



<sup>\*10</sup> Applicable divisions correspond to output terminals.

<sup>\*</sup> These parameters are not guaranteed performance, but general specifications of each optical element which makes up a hologram laser.

Hologram Lasers GH5R495A3C

# Optical Characteristics of Hologram Device (Design Standard\*)

 $(Tc=25^{\circ}C)$ 

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Hologram diffraction	0 th	-	λ=780nm	77	82	-	%
efficiency	±1st	-	λ=780IIII	6	7	9	%
Hologram diffraction	D1,D2	-	λ=780nm	-	21.1	-	۰
angle	Except D1,D2	-	λ=780IIII	-	26.4	-	۰
Grating diffraction efficiency		-	0:1	6.7	9	12.4	-
Grating diffraction angle		-	λ=780nm	-	2.8	-	۰

### ■ Electro-optical Characteristics of Laser Diode (Design Standard\*)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	$\Delta \mathbf{x}$		-80	-	+80	μm
Misalignment position	Δy	- [	-80	-	+80	μm
	$\Delta z$		-80	-	+80	μm

### ■ Electro-optical Characteristics of OPIC for Signal Detection (Design Standard\*)

(Tc=25°C, Vcc=5V, Vref=2.1V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit	*3 Segment
Supply voltage	Vcc	-	4.5	5	5.5	V		
Reference voltage	$V_{ref}$	-		2.00	2.1	2.21	V	
Reference voltage terminal current	Iref	Common to high/low gain, No	light	-0.5	1	2	mA	
*4,5,8,7 Response frequency	fcm	Common to high/low gain, -3	dB	45	60	-	MHz	Α
Response frequency	fcs	Common to high/low gain, -3	dB	1	2	-	MHz	В
*4,6,7 Peaking level	Vpk2	Common to high/low gain f=0.1 to 45MHz	-	-	3	dB	A	
*7 Noise level	fnm	Hign gain, 50 Ω end BW=30kHz, f=28.8MHz	-	-74	-68	dBm	A	
Sensitivity 1	R <sub>m</sub> 1	Main amp, Hign gain		18	24	30	mV/μW	Α
Sensitivity 2	R <sub>m</sub> 2	Main amp, Low gain		0.72	0.96	1.2	mV/μW	A
Sensitivity 3	R <sub>m</sub> 3	Sub amp, Hign gain		72	96	120	mV/μW	В
Sensitivity 4	R <sub>m</sub> 4	Sub amp, Low gain		2.88	3.84	4.8	$mV/\mu W$	В
Settling time	<b>t</b> set	'	6.9 Hz	-	30	-	ns	A
Maximum output voltage	V₀max	Common to high/low gain, Vref refe	rence	1	i	-	V	A, B

<sup>\*3</sup> Appricable divisions correspond to output terminals.

 $A: V_A, V_B, V_C, V_D$ 

 $B: V_{E+G}, V_{F+H}$ 

<sup>\*4</sup> Light source is a laser diode of  $\lambda$ =780nm.

<sup>\*5 -3</sup>dB level (0dB level is taken for output level when f=0.1MHz)

<sup>\*6 10</sup>μW of DC light is applied to the center of each photodiode, and 4μW of AC light is irradiated. BW=10kHz

 $<sup>^{97}</sup>$  5k $\Omega$  of resistor and 10pF of capacitor should be connected in parallel between output terminal and Vref terminal.

<sup>\*</sup> These parameters are not guaranteed performance, but general specifications of each optical element which makes up a hologram laser.

<sup>•</sup> Please refer to the chapter "Handling Precautions"

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